

Study of NASICON Structured Lithium Ion Conductor $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$

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Abstract. NASICON structured $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ have been studied to replace LAGP and LATP in this paper. The effects of both annealing temperature and Al doping were investigated. Both the annealing temperature and Al doping exhibited an optimal value, which is 1100°C and 0.3, respectively. The doping of Al helped $\text{LiZr}_2(\text{PO}_4)_3$ transfer from triclinic phase to rhombohedral phase and the conductivity of doped one was improved by one order of magnitude.

Introduction

Lithium-ion batteries have been given ever increasing attention due to their high energy density, long cycle life and environment-friendly feature. Limitations of the flammable organic liquid electrolytes of the Li-ion batteries, such as safety concerns, leakage, corrosion and miniaturization difficulty, have made inorganic solid lithium ion conductors the research hotspot. Inorganic solid lithium ion conductors studied intensively include perovskite type, NASICON type, LISICON type and garnet type [1].

The overall performance of NASICON structured lithium ion conductors made them possible alternatives to organic liquid electrolytes. NASICON materials have a general formula $\text{Li}_{1+x}\text{M}'_x\text{M}''_{2-x}(\text{PO}_4)_3$, of which $\text{Li}_{1+x}\text{Al}_x\text{Ti}_{2-x}(\text{PO}_4)_3$ (LATP) and $\text{Li}_{1+x}\text{Al}_x\text{Ge}_{2-x}(\text{PO}_4)_3$ (LAGP) exhibit conductivities in the range of 10^{-3} - 10^{-4} S/cm [2-4].

With its optimal ion conductive path size, the ionic conductivity of LATP system is higher than LAGP system at room temperature, but Ti^{4+} can be reduced to Ti^{3+} when in contact with lithium and thus the overall performance will be harmed. Germanium is expensive and therefore limits its applications of massive production. Zirconium, having the same valence as Ti^{4+} and Ge^{4+} and even bigger ionic radius, are stable and relatively cheap, which makes it a possibly suitable candidate to replace Ti^{4+} and Ge^{4+} . Therefore, $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ system has been studied and the effects of Al doping and annealing temperature have been investigated in this paper.

Experimental

$\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ materials with varied amounts of Al doping ($x=0, 0.1, 0.2, 0.3, 0.4, 0.5, 0.6, 0.7$ and 0.8) has been prepared by solid state reaction method in this study. Start materials used are Li_2CO_3 ($\geq 99\%$), $\text{Al}(\text{OH})_3$ ($\geq 99\%$), ZrO_2 ($\geq 99\%$) and $\text{NH}_4\text{H}_2\text{PO}_4$ ($\geq 99\%$). For each composition, stoichiometric starting materials were weighed and mixed thoroughly in a pestle mortar. Then all the mixtures were calcined at 700°C for 2 hours to remove volatile components and then pressed into pellets. All the pellets were sintered subsequently at 900°C, 1100°C and 1150°C for 2 hours to study effects of the doping amount of aluminum and annealing temperature.

All the sintered pellets were polished and painted with silver paste on both sides for electrochemical impedance spectra (EIS) analysis. The EIS measurements were carried out using a PARSTAT2273 station by applying an amplitude of 10mV. The frequency range was 0.1Hz to 2×10^6 Hz.

The microstructures were examined by using an atomic force microscopy (CSPM5500). Crystallographic phases analysis was carried out by X-ray diffraction with a D/max-2500J/pc diffractometer using a Cu K-radiation source ($\lambda=0.15418\text{nm}$).

Results and Discussion

Microstructure Examinations. All the samples have been examined by using AFM. It was found that Al doping has little influences on the microstructures of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$. While the microstructures of samples, despite of its Al amount, is strongly affected by the annealing temperature. Therefore, only AFM images of $\text{Li}_{1.5}\text{Al}_{0.5}\text{Zr}_{1.5}(\text{PO}_4)_3$ samples annealed at 900°C, 1100°C and 1150°C are shown in Fig.1. The samples annealed at 900°C showed a powdery morphology and no well-defined grains were found on the surface, while the samples annealed at 1100°C started to exhibit a mixed morphology of well-defined grains and powdery regions. For the samples annealed at 1150°C, the morphology is typical features of crystalline material with well-defined grains and grain boundaries. This is in well agreement with the theory of sintering which states thermal annealing should be able to produce the growth of contacts between particles and their coalescence.

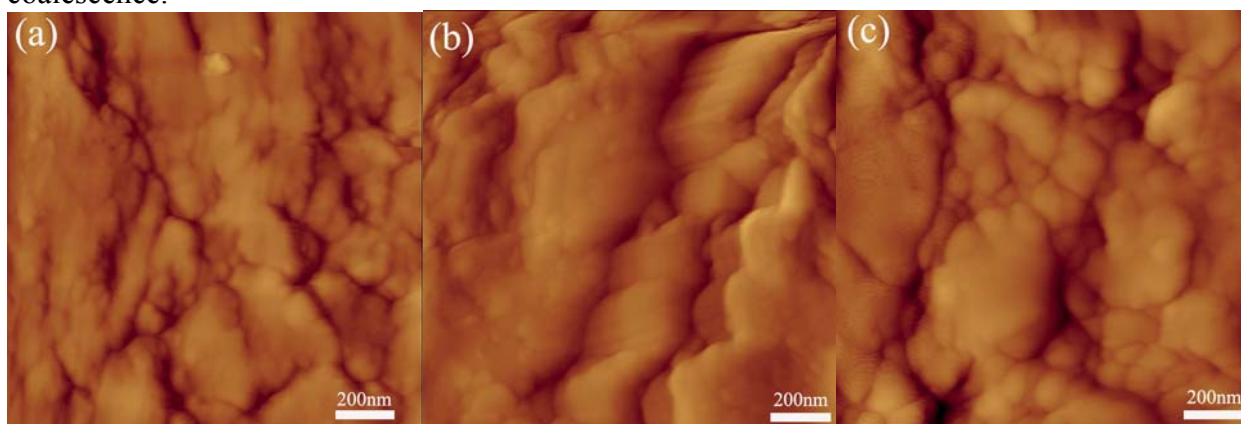


Fig.1 AFM images of $\text{Li}_{1.5}\text{Al}_{0.5}\text{Zr}_{1.5}(\text{PO}_4)_3$ annealed at (a) 900°C, (b) 1100°C and (c) 1150°C

Electrochemical Impedance Spectra Analysis. The impedances of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ samples annealed at 900°C, 1100°C and 1150°C have been measured by applying an amplitude of 10mV, Nyquist plots of $\text{Li}_{1.3}\text{Al}_{0.3}\text{Zr}_{1.7}(\text{PO}_4)_3$, $\text{Li}_{1.5}\text{Al}_{0.5}\text{Zr}_{1.5}(\text{PO}_4)_3$, $\text{Li}_{1.7}\text{Al}_{0.7}\text{Zr}_{1.3}(\text{PO}_4)_3$ are shown in Fig.2-4. All the impedance spectra are shown as a semicircle followed by a tail, which are typical spectra of ionic conductors. It also can be seen from these spectra that the semicircles of the samples annealed at 900°C are the largest, the ones of the samples annealed at 1150°C rank the second and the ones at 1100°C are the smallest. Since all the samples have similar dimensions, the semicircles represent the conductivity qualitatively at some degree, which means the conductivities of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ reached the maximum at 1100°C and then decreased slightly at 1150°C. Therefore it can be concluded that there is an optimal annealing temperature, which is 1100°C, for $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ samples.

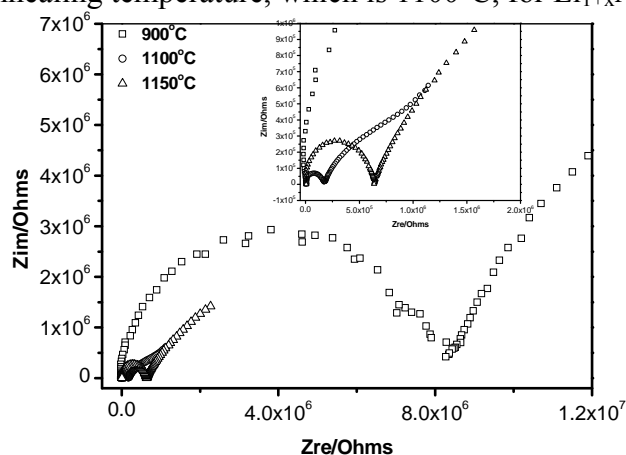


Fig.2 Nyquist plots of $\text{Li}_{1.3}\text{Al}_{0.3}\text{Zr}_{1.7}(\text{PO}_4)_3$ samples annealed at various temperatures (Inset is the enlarged part of high frequency)

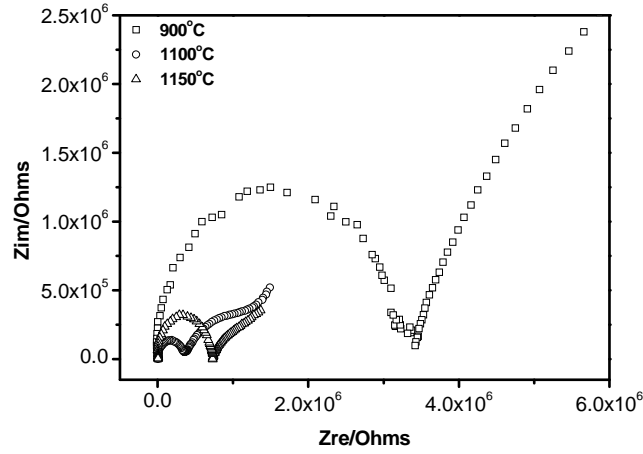


Fig.3 Nyquist plots of $\text{Li}_{1.5}\text{Al}_{0.5}\text{Zr}_{1.5}(\text{PO}_4)_3$ samples annealed at various temperatures

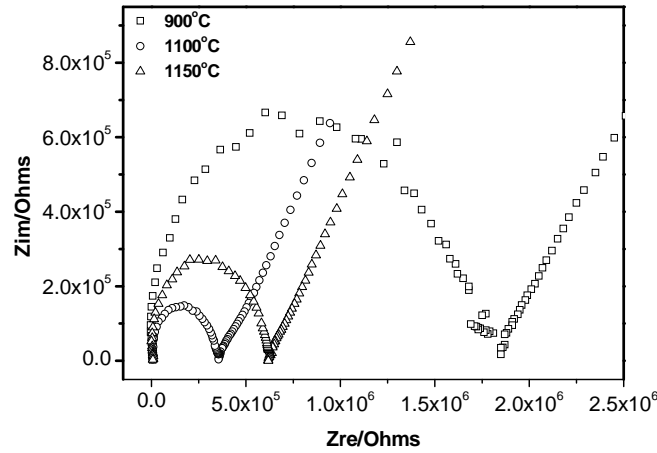


Fig.4 Nyquist plots of $\text{Li}_{1.7}\text{Al}_{0.7}\text{Zr}_{1.3}(\text{PO}_4)_3$ samples annealed at various temperatures

Nyquist plots of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ samples annealed at 1100°C are shown in Fig.5. The impedance of all the samples doped with Al decreased compared to the ones without Al doping. It means Al dopant helped to increase the conductivities of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ possibly by introducing extra Li^+ in the system. While the decreasing of impedance did not show a linear trend with Al doping amount, it reached the lowest when $x=0.3$. Since it is difficult to distinct grain response from grain boundary response in Nyquist plots, overall ionic conductivities were calculated using Eq.1 as follows.

$$\sigma = \frac{1}{R} \times \frac{h}{S} \quad (1)$$

where σ is conductivity in S/cm; h is the thickness of the pellet in cm; S is the electrode area in cm^2 ; R is the impedances measured in Ω . According to Eq. 1, the overall conductivity of $\text{Li}_{1.3}\text{Al}_{0.3}\text{Zr}_{1.7}(\text{PO}_4)_3$ is $1.6 \times 10^{-6} \text{ S/cm}$ and the overall conductivity of $\text{LiZr}_2(\text{PO}_4)_3$ is $1.97 \times 10^{-7} \text{ S/cm}$. The conductivity is improved almost by one order of magnitude when doped with Al. XRD patterns show that crystallographic phase of $\text{LiZr}_2(\text{PO}_4)_3$ is triclinic while the samples doped with Al is rhombohedral. Therefore the conductivity measurement is in agreement with the fact that the triclinic phase shows a lower conductivity than the rhombohedral [5-7].

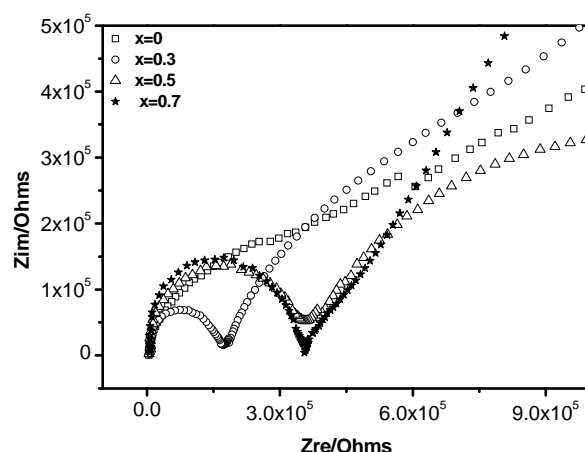


Fig.5 Nyquist plots of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ samples annealed at 1100°C

Conclusions

NASICON structured lithium ion conductor $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ has been studied in this paper. The effects of annealing temperature and the doping of Al were investigated. It was found that there is an optimal value for both annealing temperature and Al doping. For the same amount of Al doping, the conductivity reached the maximum at 1100°C . The conductivities of $\text{Li}_{1+x}\text{Al}_x\text{Zr}_{2-x}(\text{PO}_4)_3$ system studied achieved the highest of $1.6 \times 10^{-6} \text{ S/cm}$, which is one order of magnitude higher than that of undoped ones. XRD examinations showed that Al doping helped $\text{LiZr}_2(\text{PO}_4)_3$ transfer from triclinic phase to rhombohedral phase.

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